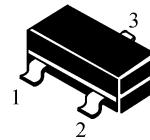


PNP Switching Transistor

SOT-23

1. BASE
2. Emitter
3. COLLECTOR



■MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
Collector-Emitter Voltage	V _{CEO}	-40	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-6.0	Vdc
Collector Current-Continuous	I _c	-200	mAdc

■THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board(1) TA=25°C Derate above25°C	P _D	225 1.8	mW mW/°C
Total Device Dissipation Alumina Substrate, TA=25°C Derate above25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance Junction to Ambient	R _{θJA}	417	°C/W
Junction and Storage Temperature	T _{J,Tstg}	150°C, -55to+150°C	

■ ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

■ OFF CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage(3) ($I_C = -1.0\text{mA}_\text{dc}, I_B = 0$)	$V_{(\text{BR})\text{CEO}}$	-40	—	Vdc
Collector-Base Breakdown Voltage ($I_C = -10 \mu\text{A}_\text{dc}, I_E = 0$)	$V_{(\text{BR})\text{CBO}}$	-40	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = -10 \mu\text{A}_\text{dc}, I_C = 0$)	$V_{(\text{BR})\text{EBO}}$	-6.0	—	Vdc
Base Cutoff Current ($V_{CE} = -30\text{Vdc}, V_{EB} = -3.0\text{Vdc}$)	$I_{B\text{EX}}$	—	-50	nAdc
Collector Cutoff Current ($V_{CE} = -30\text{Vdc}, V_{EB} = -3.0\text{Vdc}$)	$I_{C\text{EX}}$	—	-50	nAdc

■ ON CHARCTERISTICS(2)

Characteristic	Symbol	Min	Max	Unit
DC Current Gain ($I_C = -0.1\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)	h_{PE}			—
($I_C = -1.0\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)		40	—	
($I_C = -10\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)		70	—	
($I_C = -100\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)		100	300	
($I_C = -50\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)		60	—	
($I_C = -10\text{mA}_\text{dc}, V_{CE} = -1.0\text{Vdc}$)		30	—	
Collector-Emitter Saturation Voltage ($I_C = -10\text{mA}_\text{dc}, I_B = -1.0\text{mA}_\text{dc}$) ($I_C = -50\text{mA}_\text{dc}, I_B = -5.0\text{mA}_\text{dc}$)	$V_{CE(\text{sat})}$	— —	-0.25 -0.4	Vdc
Base-Emitter Saturation Voltage ($I_C = -10\text{mA}_\text{dc}, I_B = -1.0\text{mA}_\text{dc}$) ($I_C = -50\text{mA}_\text{dc}, I_B = -5.0\text{mA}_\text{dc}$)	$V_{BE(\text{sat})}$	-0.65 —	-0.85 -0.95	Vdc

■ SMALL-SIGNAL CHARACTERISTICS

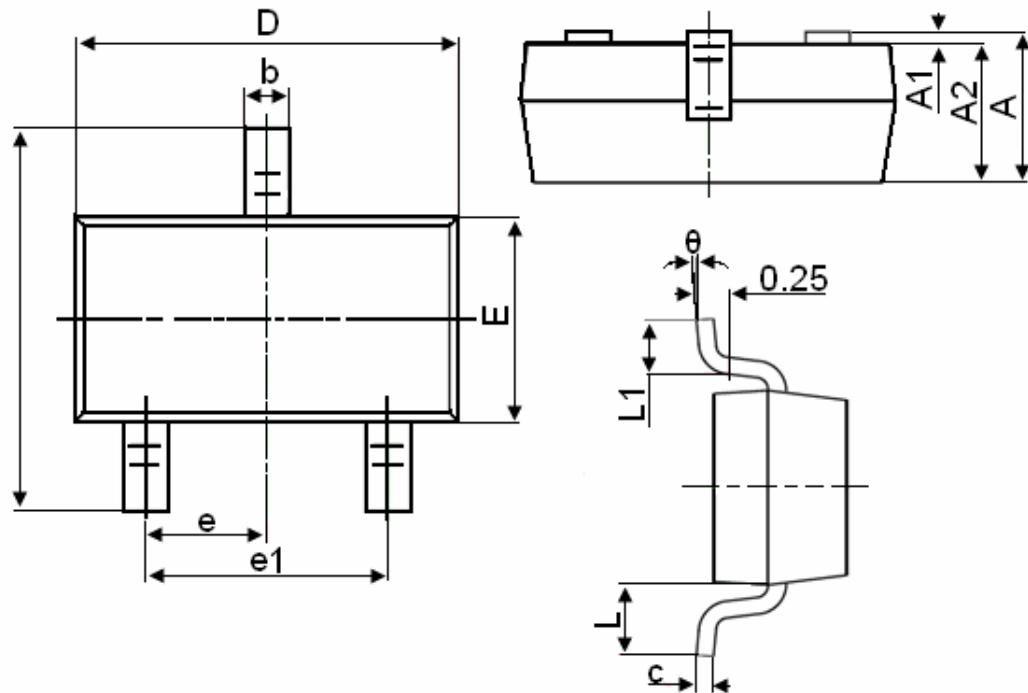
Characteristic	Symbol	Min	Max	Unit
Current-Gain-Bandwidth Product ($I_C=-10\text{mA}_{\text{dc}}$, $V_{CE}=-20\text{V}_{\text{dc}}$, $f=100\text{MHz}$)	f_T	300	—	MHz
Output Capacitance ($V_{CB}=-5.0\text{V}_{\text{dc}}$, $I_E=0$, $f=1.0\text{MHz}$)	C_{obo}	—	4.0	pF
Input Capacitance ($V_{EB}=-0.5\text{V}_{\text{dc}}$, $I_C=0$, $f=1.0\text{MHz}$)	C_{ibo}	—	8.0	pF
Input Impedance ($V_{CE}=-10\text{V}_{\text{dc}}$, $I_C=-1.0\text{mA}_{\text{dc}}$, $f=1.0\text{KHz}$)	h_{ie}	1.0	10	k Ω
Voltage Feedback Ratio ($V_{CE}=-10\text{V}_{\text{dc}}$, $I_C=-1.0\text{mA}_{\text{dc}}$, $f=1.0\text{KHz}$)	h_{re}	0.5	8.0	$\times 10^{-4}$
Small-Signal Current Gain ($V_{CE}=-10\text{V}_{\text{dc}}$, $I_C=-1.0\text{mA}_{\text{dc}}$, $f=1.0\text{KHz}$)	h_{fe}	100	400	—
Output Admittance ($V_{CE}=-10\text{V}_{\text{dc}}$, $I_C=-1.0\text{mA}_{\text{dc}}$, $f=1.0\text{KHz}$)	h_{oe}	1.0	40	μmhos
Noise Figure ($V_{CE}=-5.0\text{V}_{\text{dc}}$, $I_C=-100 \mu \text{A}_{\text{dc}}$, $R_s=1.0 \text{k}\Omega$, $f=1.0\text{KHz}$)	NF	—	5.0	dB

■ SWITCHING CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Delay Time	t_d	—	35	ns
Rise Time	t_r	—	35	
Storage Time	t_s	—	225	ns
Fall Time	t_f	—	75	

- FR-5=1.0×0.75×0.062in.
- Alumina=0.4×0.3×0.024in. 99.5%alumina.
- Pulse Width \leq 300us; Duty Cycle \leq 2.0%.
- Pulse Test: Pulse Width \leq 300us; Duty Cycle \leq 2.0%.

SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

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